

The OHD^P30CA is a high-output, high-speed silicon photodiode, mounted in durable hermetically sealed T0-8F metal can package, which provides years of reliable performance even under demanding conditions such as use outdoors.

FEATURES

- High-output power
- High-speed response
- Durable
- High reliability in demanding environments



APPLICATIONS

- Infrared sensors
- Optical detectors
- Optical switches

ELECTRO-OPTICAL CHARACTERISTICS

(Ta=25°C)

Item	Symbol	Cond.	Min.	Typ.	Max.	Unit
Open circuit voltage	V _{oc}	Ev=1,000Lux		0.3		V
Short circuit current	I _{sc}			65.0		μA
Dark current	I _d	V _R =10V			0.1	μA
Curve factor	C.F		0.55			—
Capacitance	C _t	V=0V, f=1MHz		155		PF
Temperature coefficient of V _{oc}	α t			-2.2		mV/°C
Temperature coefficient of I _{sc}	β t			0.18		%/°C
Spectral sensitivity	λ		450~1,050			nm
Peak wavelength	λ _p			900		nm
Half angle	Δ θ			±55		deg.

MAXIMUM RATINGS

(Ta=25°C)

Item	Symbol	Rating	Unit
Reverse voltage	V _R	10	V
Operating temp.	T _{opr.}	-25~+100	°C
Storage temp.	T _{stg.}	-30~+100	°C
Soldering temp. ⁽¹⁾	T _{sol.}	260	°C

(1)For MAX.5seconds at the position of 2mm from the package

